

1.8V CMOS Low Jitter Crystal Clock Oscillator (XO)



Product Features

- Less than 1.5 ps RMS jitter with fundamental or overtone design
- 1.8V CMOS compatible logic levels
- Pin-compatible with standard 3.2x5mm packages
- Designed for standard reflow and washing techniques
- Low power standby mode: 10 uA max
- Pb-free and RoHS/Green compliant

Product Description

The S1632 Series is a 1.8V crystal clock oscillator that achieves superb jitter and stability over a broad range of operating conditions and frequencies. The output clock signal, generated internally with a non-PLL oscillator design, is compatible with LVCMOS logic levels. The device, available on tape and reel, is contained in a 3.2x5mm surface-mount ceramic package.

Applications

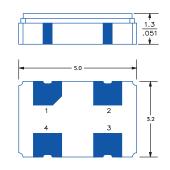
The S1632 Series is an ideal reference clock for compact, high-density applications requiring low jitter tight stability, or low power consumption, including:

- Ethernet
- HBA
- Portable Multimedia Player (PMP)
- Notebook Computer
- Hard Disk Drive





Packaging Outline



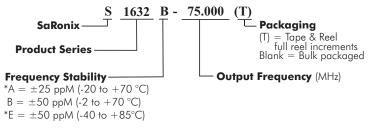
Pin Functions			
Pin	Function		
1	OE Function		
2	Ground		
3	Clock Output		
4	V _{DD}		

Common Frequencies

Contact SaRonix for additional frequencies

2.0480 MHz	24.0000 MHz	50.0000 MHz
3.6864 MHz	24.5760 MHz	60.0000 MHz
8.0000 MHz	25.0000 MHz	66.0000 MHz
10.0000 MHz	27.0000 MHz	66.6667 MHz
14.3181 MHz	32.0000 MHz	75.0000 MHz
16.0000 MHz	33.0000 MHz	80.0000 MHz
19.4400 MHz	40.0000 MHz	90.0000 MHz
20.0000 MHz	48.0000 MHz	100.0000 MHz

Ordering Information



* Availability varies by frequency.

Pericom Semiconductor Corporation • 1-800-435-2336 • http://www.pericom.com/saronix

PERICOM Semiconductor Corporation

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Electrical Performance

Pc	ırameter	Min.	Тур.	Max.	Units	Notes
Output freque	ıcy	1.5440		100	MHz	As specified
Supply voltage		1.71	1.8	1.89	V	
				4	mA	1.5440 to <36 MHz
S				7		36 to <50 MHz
Supply current	, output enabled			10		50 to <70 MHz
				20		70 to 100 MHz
Standby currer	nt			10	μA	1.5440 to <36MHz
				100	uA	36 to 100MHz
Frequency stat	oility			±25 to ±50	ррМ	See Note 1 below
Operating tem	perature	-40		+85	°C	As specified
Output logic 0,	VOL			10% V _{DD}	V	
Output logic 1,	VOH	90% V _{DD}			V	
Output load		15 pF (max)				
Duty cycle		45		55	%	measured 50%VDD
Rise and fall	<36 MHz			4		measured 20/80% of waveform
time	36 to 100 MHz			2.5	ns	measured 20/80% of waveform
Jitter,	up to 75 MHz			1.5	ps RMS	10kHz to 20 MHz frequency band
Phase	75 to 100 MHz			1	(1-σ)	
Jitter,	up to <75 MHz			5	ps RMS	20.000 adjacent periods
Accumulated	75 to 100 MHz			3	(1-σ)	
Jitter,	up to <75 MHz			50	ps	100.000 random periods
Total	75 to 100 MHz			30	pk-pk	

Notes:

1. As specified. Stability includes all combinations of operating temperature, load changes, rated input (supply) voltage changes, initial calibration tolerance (25°C), aging (1 year at 25°C average effective ambient temperature), shock and vibration.

Output Enable / Disable Function

Parameter	Min.	Тур.	Max.	Units	Notes
Input Voltage (pin 1), Output Enable	0.7 V _{DD}			V	or open
Input voltage (pin 1), Output Disable (low power standby)			0.3 V _{DD}	V	Output is Hi-Z
Internal pullup resistance	30			kΩ	
Output disable delay			200	ns	
Output enable delay			10	ms	



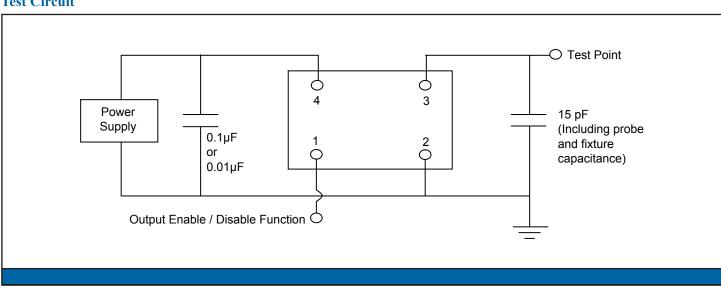


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Absolute Maximum Ratings

Parameter	Min.	Тур.	Max.	Units	Notes
Storage temperature	-55		+125	°C	

Test Circuit



Reliability Test Ratings

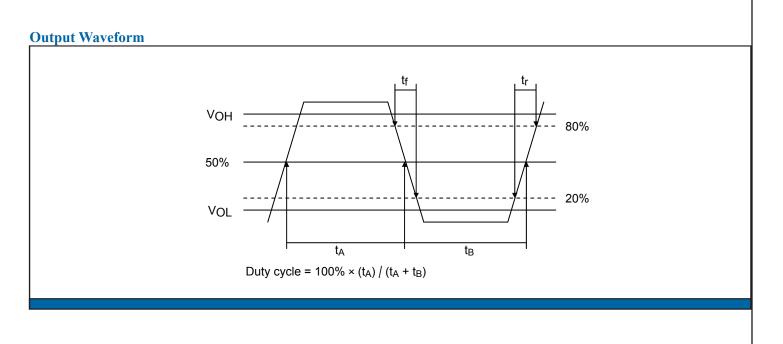
This product is rated to meet the following test conditions:

Туре	Parameter	Test Condition
Mechanical	Shock	MIL-STD-883, Method 2002, Condition B
Mechanical	Solderability	JESD22-B102-D Method 2 (Preconditioning E)
Mechanical	Terminal strength	MIL-STD-883, Method 2004, Condition D
Mechanical	Gross leak	MIL-STD-883, Method 1014, Condition C
Mechanical	Fine leak	MIL-STD-883, Method 1014, Condition A2 ($R_1 = 2x10^{-8}$ atm cc/s)
Mechanical	Solvent resistance	MIL-STD-202, Method 215
Environmental	Thermal shock	MIL-STD-883, Method 1011, Condition A
Environmental	Moisture resistance	MIL-STD-883, Method 1004
Environmental	Vibration	MIL-STD-883, Method 2007, Condition A
Environmental	Resistance to soldering heat	J-STD-020C Table 5-2 Pb-free devices (2 cycles max)



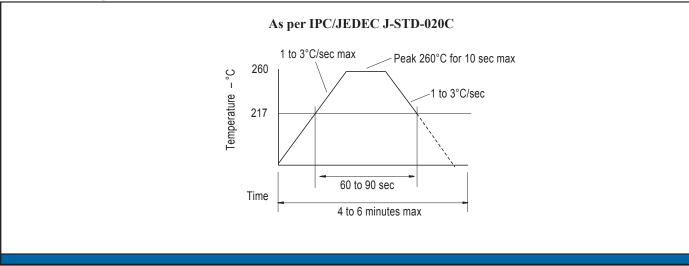


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Reflow Soldering Profile

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Mechanical Drawings

